

ESD Protection Diode NSPM0061

1 0 0 2 Cathode Anode

Features

- Protection for the following IEC Standards: IEC61000-4-2 Level 4: ±30 kV Contact Discharge IEC61000-4-5 (Lightning) 70 A (8/20 μs)
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

CASE 517CZ

MARKING DIAGRAM



F = Specific Device Code = Date Code

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	ORDERING INF
IEC 61000-4-2 (ESD) Contac Ai		±30 ±30	kV	Device Pack
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C	NSPM0061MUT5G UDF (Pb-F
Maximum Peak Pulse Current 8/20 μs @ T _A = 25°C	Ірр	70	A	t For information on tape an including part orientation a refer to our Tape and Reel
device. If any of these limits are exceeded assumed, damage may occur and reliability	may be affe		ME	YOUR ORMAI!

ORDERING INFORMATION

Device	Package	Shipping [†]
NSPM0061MUT5G	UDFN2	8000 / Tape &
	(Pb-Free)	Reel

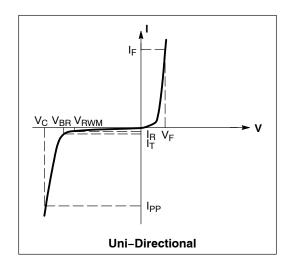
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

Symbol	Parameter
Ipp	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
I _T	Test Current

^{*}See Application Note AND8308/D for detailed explanations of data sheet parameters.



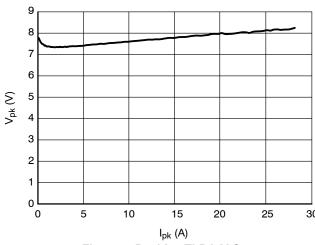
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Parameter	Symbol	Conditions Min	Тур	Max	Unit
Reverse Working Voltage	V_{RWM}		100	6.3	٧
Breakdown Voltage (Note 1)	V_{BR}	I _T = 1 mA 6.5	7.3	9.0	٧
Reverse Leakage Current	I _R	V _{RWM} = 6.3 V		1	μΑ
Clamping Voltage (Note 2)	V _C	I _{PP} = 1 A, t _p = 8 x 20 µs	mo 1	7.5	٧
Clamping Voltage (Note 2)	V _C	I _{PP} = 35 A, t _p = 8 x 20 μs	10,	9.5	٧
Clamping Voltage (Note 2)	V _C	I _{PP} = 70 A, t _p = 8 x 20 µs		11.5	٧
Junction Capacitance	CJ	V _R = 0 V, f = 1 MHz	12		pF
Dynamic Resistance	R_{DYN}	TLP Pulse	0.04		Ω

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. performance may not be indicated by the Electrical Characteristics if operated

1. Breakdown voltage is tested from pin 1 to 2 and pin 2 to 1.

2. Non-repetitive current pulse at T_A = 25°C, per IEC61000-4-5 waveform.



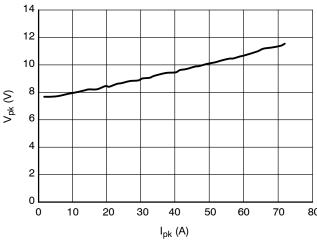
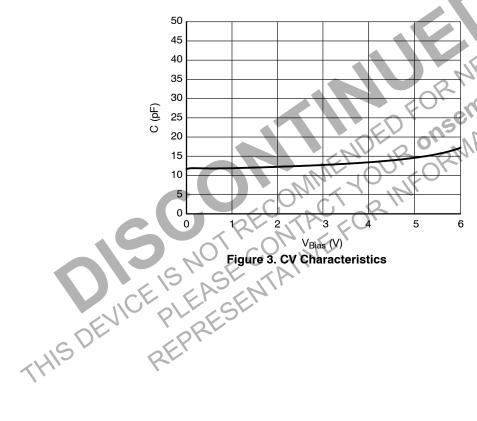


Figure 1. Positive TLP I-V Curve

Figure 2. Clamping Voltage vs. Peak Pulse Current ($t_p = 8/20 \mu s$)



Transmission Line Pulse (TLP) Measurement

Transmission Line Pulse (TLP) provides current versus voltage (I-V) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 4. TLP I-V curves of ESD protection devices accurately demonstrate the product's ESD capability because the 10s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 5 where an 8 kV IEC 61000-4-2 current waveform is compared with TLP current pulses at 8 A and 16 A. A TLP I-V curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels. For more information on TLP measurements and how to interpret them please refer to AND9007/D.

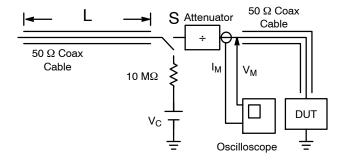
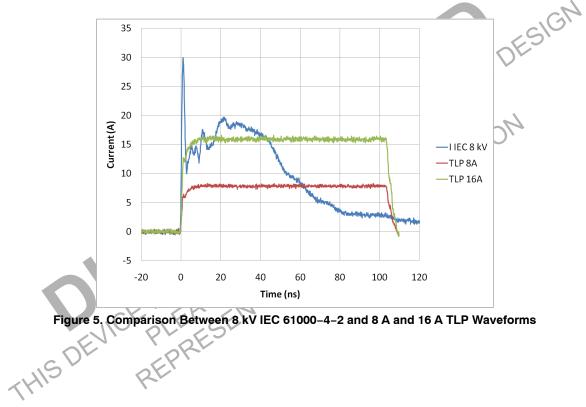


Figure 4. Simplified Schematic of a Typical TLP **System**



IEC 61000-4-2 Spec.

Level	Test Volt- age (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

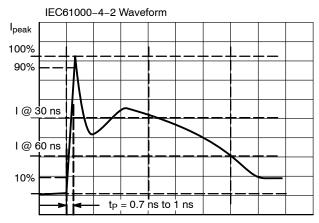


Figure 6. IEC61000-4-2 Spec

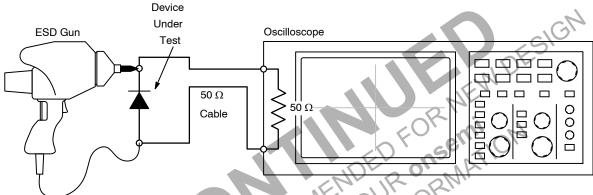


Figure 7. Diagram of ESD Test Setup

ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger systems such as cell phones or laptop computers it is not

clearly defined in the spec how to specify a clamping voltage at the device level. **onsemi** has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the data sheets for all ESD protection diodes. For more information on how **onsemi** creates these screenshots and how to interpret them please refer to AND8307/D.

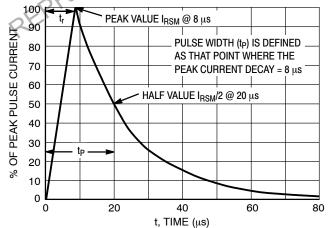
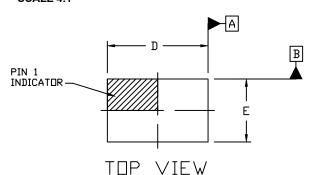


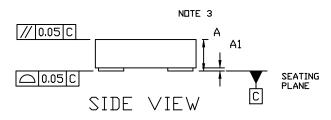
Figure 8. 8 x 20 µs Pulse Waveform

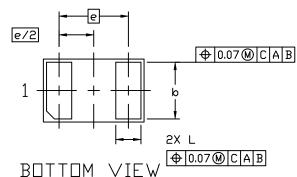


UDFN2 1.6x1.0, 1.1P CASE 517CZ ISSUE D

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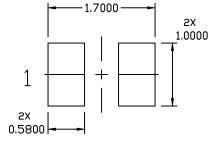




NDTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS

	MILLIMETERS			
DIM	MIN.	N□M.	MAX.	
Α	0.45	0.50	0.55	
A1			0.05	
b	0.83	0.88	0.93	
D	1.52	1.60	1.68	
E	0.92	1.00	1.08	
е	1.10 BSC			
L	0.35	0.40	0.45	



RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the IIN Semiconductor Soldering and Mounting Techniques Reference Manual, SILDERRM/D.

GENERIC MARKING DIAGRAM*



XX = Specific Device Code M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present. Some products may not follow the Generic Marking.

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